8-bit addressable latch

Rev. 1 — 22 July 2013

**Product data sheet** 

## 1. General description

The 74AHC259-Q100; 74AHCT259-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7-A.

The 74AHC259-Q100; 74AHCT259-Q100 is a high-speed 8-bit addressable latch designed for general purpose storage applications in digital systems. It is a multifunctional device capable of storing single-line data in eight addressable latches. It provides a 3-to-8 decoder and multiplexer function with active HIGH outputs (Q0 to Q7). It also incorporates an active LOW common reset (MR) for resetting all latches as well as an active LOW enable input ( $\overline{LE}$ ).

The 74AHC259-Q100; 74AHCT259-Q100 has four modes of operation:

- In the addressable latch mode, data on the data line (D) is written into the addressed latch. The addressed latch follows the data input with all non-addressed latches remaining in their previous states.
- In the memory mode, all latches remain in their previous states and are unaffected by the data or address inputs.
- In the 3-to-8 decoding or demultiplexing mode, the addressed output follows the state of the data input (D) with all other outputs in the LOW state.
- In the reset mode, all outputs are LOW and unaffected by the address inputs (A0 to A2) and data input (D).

When operating the 74AHC259-Q100; 74AHCT259-Q100 as an address latch, changing more than 1 bit of the address could impose a transient-wrong address. Therefore, only change more than 1 bit while in the memory mode.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Combines demultiplexer and 8-bit latch
- Serial-to-parallel capability



- Output from each storage bit available
- Random (addressable) data entry
- Easily expandable
- Common reset input
- Useful as a 3-to-8 active HIGH decoder
- Inputs accept voltages higher than V<sub>CC</sub>
- Input levels:
  - For 74AHC259-Q100: CMOS level
  - For 74AHCT259-Q100: TTL level
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

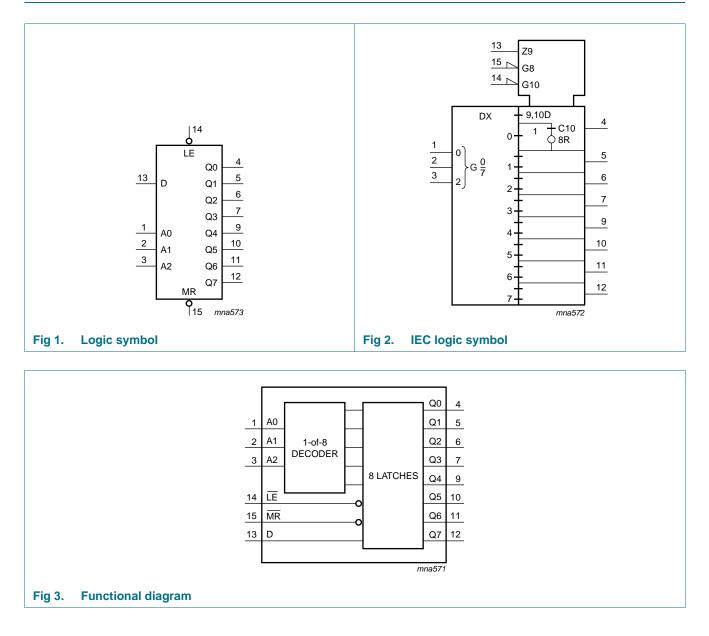
## 3. Ordering information

#### Table 1.Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AHC259-Q100				
74AHC259D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHC259PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74AHCT259-Q100				
74AHCT259D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHCT259PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

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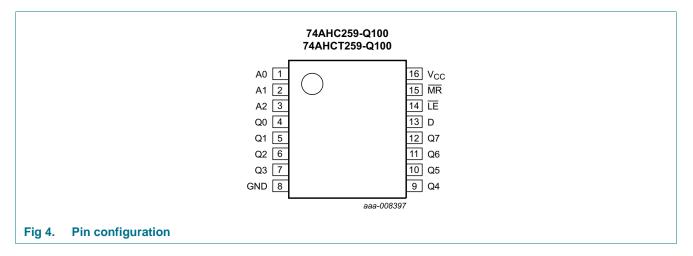
## 4. Functional diagram



8-bit addressable latch

## 5. Pinning information

## 5.1 Pinning



## 5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
A0	1	address input
A1	2	address input
A2	3	address input
Q0	4	latch output
Q1	5	latch output
Q2	6	latch output
Q3	7	latch output
GND	8	ground (0 V)
Q4	9	latch output
Q5	10	latch output
Q6	11	latch output
Q7	12	latch output
D	13	data input
LE	14	latch enable input (active LOW)
MR	15	conditional reset input (active LOW)
V <sub>CC</sub>	16	supply voltage

## 6. Functional description

#### Table 3.Function table

Operating mode	Inpu	It					Outpu	It						
	MR	LE	D	A0	A1	A2	Q0	Q1	Q2	Q3	Q4	Q5	Q6	Q7
Reset (clear)	L	Н	Х	Х	Х	Х	L	L	L	L	L	L	L	L
Demultiplexer	L	L	d	L	L	L	Q = d	L	L	L	L	L	L	L
(active HIGH 8-channel) decoder (when $D = H$ )			d	Н	L	L	L	Q = d	L	L	L	L	L	L
			d	L	Н	L	L	L	Q = d	L	L	L	L	L
			d	Н	Н	L	L	L	L	Q = d	L	L	L	L
			d	L	L	Н	L	L	L	L	Q = d	L	L	L
			d	Н	L	Н	L	L	L	L	L	Q = d	L	L
			d	L	Н	Н	L	L	L	L	L	L	Q = d	L
			d	Н	Н	Н	L	L	L	L	L	L	L	Q = d
Memory (no action)	Н	Н	Х	Х	Х	Х	<b>q</b> 0	<b>q</b> <sub>1</sub>	q <sub>2</sub>	$q_3$	$q_4$	$q_5$	<b>q</b> <sub>6</sub>	<b>q</b> <sub>7</sub>
Addressable latch	Н	L	d	L	L	L	Q = d	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	<b>q</b> <sub>4</sub>	<b>q</b> 5	<b>q</b> <sub>6</sub>	<b>q</b> 7
			d	Н	L	L	<b>q</b> 0	Q = d	q <sub>2</sub>	q <sub>3</sub>	q <sub>4</sub>	<b>q</b> 5	q <sub>6</sub>	<b>q</b> 7
			d	L	Н	L	<b>q</b> 0	q <sub>1</sub>	Q = d	q <sub>3</sub>	<b>q</b> <sub>4</sub>	<b>q</b> 5	<b>q</b> <sub>6</sub>	<b>q</b> 7
			d	Н	Н	L	<b>q</b> 0	<b>q</b> <sub>1</sub>	q <sub>2</sub>	Q = d	q <sub>4</sub>	<b>q</b> 5	q <sub>6</sub>	<b>q</b> 7
			d	L	L	Н	<b>q</b> 0	<b>q</b> <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	Q = d	<b>q</b> 5	q <sub>6</sub>	<b>q</b> 7
			d	Н	L	Н	<b>q</b> <sub>0</sub>	q <sub>1</sub>	q <sub>2</sub>	$q_3$	<b>q</b> <sub>4</sub>	Q = d	<b>q</b> <sub>6</sub>	<b>q</b> 7
			d	L	Н	Н	<b>q</b> 0	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	<b>q</b> <sub>4</sub>	<b>q</b> <sub>5</sub>	Q = d	<b>q</b> 7
			Н	Н	Н	Н	<b>q</b> 0	<b>q</b> <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	<b>q</b> <sub>4</sub>	$q_5$	<b>q</b> <sub>6</sub>	Q = d

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

d = HIGH or LOW data one set-up time prior to the LOW-to-HIGH  $\overline{\text{LE}}$  transition;

q = lower case letter indicates the state of the referenced input one set-up time prior to the LOW-to-HIGH transition.

Table 4.	Operating mode sele	ct table[1]
LE	MR	Mode
L	Н	addressable latch
Н	Н	memory
L	L	active HIGH 8-channel demultiplexer
Н	L	reset

[1] H = HIGH voltage level; L = LOW voltage level.

## 7. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	<u>[1]</u> –20	-	mA
Ι <sub>ΟΚ</sub>	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> –20	+20	mA
lo	output current	$V_{O}$ = -0.5 V to (V <sub>CC</sub> + 0.5 V)	-25	+25	mA
I <sub>CC</sub>	supply current		-	+75	mA
I <sub>GND</sub>	ground current		-75	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[2] _	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO16 packages: above 70 °C the value of  $P_{tot}$  derates linearly at 8 mW/K.

For TSSOP16 packages: above 60  $^\circ\text{C}$  the value of  $P_{tot}$  derates linearly at 5.5 mW/K.

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## 8. Recommended operating conditions

#### Table 6. Operating conditions

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74AHC25	59-Q100					
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC}$ = 3.0 V to 3.6 V	-	-	100	ns/V
		$V_{CC}$ = 4.5 V to 5.5 V	-	-	20	ns/V
74AHCT2	259-Q100					
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	-	-	20	ns/V

## 9. Static characteristics

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C te	o +125 °C	Uni
			Min	Тур	Max	Min	Max	Min	Max	
74AHC2	59-Q100									
VIH	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_O = -50 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_0 = -50 \ \mu A; V_{CC} = 3.0 \ V$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_O = -50 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_{O}$ = -8.0 mA; $V_{CC}$ = 4.5 V	3.94	-	-	3.80	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = 50 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0$ = 4.0 mA; $V_{CC}$ = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		$I_0$ = 8.0 mA; $V_{CC}$ = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
lı	input leakage current	$V_1 = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	-	0.1	-	1.0	-	2.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	4.0	-	40	-	80	μA
Cı	input capacitance	$V_1 = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF
74AHCT	259-Q100									
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level	$V_{CC}$ = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V <sub>он</sub>	HIGH-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$								
<b>.</b>	output voltage	$I_{O} = -50 \ \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -8.0 \text{ mA}$	3.94	-	-	3.80	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$								
~-	output voltage	$I_0 = 50 \ \mu A$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 8.0 \text{ mA}$	-		0.36	-	0.44	-	0.55	V

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Symbol	Parameter	Conditions		25 °C		–40 °C te	o +85 °C	–40 °C to	• +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
l <sub>l</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I <sub>CC</sub>	supply current		-	-	4.0	-	40	-	80	μA
$\Delta I_{CC}$	additional supply current	per input pin; V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; other pins at V <sub>CC</sub> or GND; $I_O = 0 A$ ; V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
CI	input capacitance	$V_I = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF

#### Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

## **10.** Dynamic characteristics

#### Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 11.

		10 77									
Symbol	Parameter	Conditions			25 °C			o +85 °C	–40 °C to	o +125 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	Min	Max	
74AHC2	59-Q100										
t <sub>pd</sub>	propagation	D to Qn; see Figure 5	[2]								
	delay	$V_{CC}$ = 3.0 V to 3.6 V									
		C <sub>L</sub> = 15 pF		-	5.8	11.5	1.0	13.5	1.0	15.0	ns
		C <sub>L</sub> = 50 pF		-	7.3	14.5	1.0	17.0	1.0	18.5	ns
		$V_{CC}$ = 4.5 V to 5.5 V									
		C <sub>L</sub> = 15 pF		-	4.1	7.5	1.0	9.0	1.0	10.0	ns
		C <sub>L</sub> = 50 pF		-	5.3	9.5	1.0	11.0	1.0	12.0	ns
		An to Qn; see Figure 6	[2]								
		$V_{CC}$ = 3.0 V to 3.6 V									
		C <sub>L</sub> = 15 pF		-	7.5	14.5	1.0	17.0	1.0	18.5	ns
		C <sub>L</sub> = 50 pF		-	9.1	18.0	1.0	21.0	1.0	23.0	ns
		$V_{CC}$ = 4.5 V to 5.5 V									
		C <sub>L</sub> = 15 pF		-	5.3	9.5	1.0	11.5	1.0	12.5	ns
		C <sub>L</sub> = 50 pF		-	6.5	11.5	1.0	13.5	1.0	15.0	ns
		LE to Qn; see Figure 7	[2]								
		$V_{CC}$ = 3.0 V to 3.6 V									
		C <sub>L</sub> = 15 pF		-	6.2	12.0	1.0	14.0	1.0	15.2	ns
		C <sub>L</sub> = 50 pF		-	7.7	15.5	1.0	17.5	1.0	19.0	ns
		$V_{CC}$ = 4.5 V to 5.5 V									
		C <sub>L</sub> = 15 pF		-	4.3	8.0	1.0	9.5	1.0	10.5	ns
		C <sub>L</sub> = 50 pF		-	5.5	10.0	1.0	11.5	1.0	12.5	ns

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Symbol	Parameter	Conditions			25 °C		–40 °C t	o +85 °C	-40 °C te	o +125 °C	Un
				Min	Typ[1]	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation	MR to Qn; see Figure 8	[3]								
-	delay	$V_{CC}$ = 3.0 V to 3.6 V									
		C <sub>L</sub> = 15 pF		-	5.4	10.5	1.0	12.5	1.0	13.5	ns
		C <sub>L</sub> = 50 pF		-	7.0	13.5	1.0	15.5	1.0	17.0	ns
		$V_{CC}$ = 4.5 V to 5.5 V									
		C <sub>L</sub> = 15 pF		-	3.9	7.0	1.0	8.5	1.0	9.5	ns
		C <sub>L</sub> = 50 pF		-	5.1	9.0	1.0	10.5	1.0	11.5	ns
t <sub>W</sub>	pulse width	LE HIGH or LOW; see <u>Figure 7</u>									
		$V_{CC}$ = 3.0 V to 3.6 V		5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC}$ = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
		MR LOW; see Figure 8									
		$V_{CC}$ = 3.0 V to 3.6 V		5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC}$ = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
t <sub>su</sub>	set-up time	D, An to $\overline{\text{LE}}$ ; see Figure 9 and Figure 10									
		$V_{CC}$ = 3.0 V to 3.6 V		4.0	-	-	4.0	-	4.0	-	ns
		$V_{CC}$ = 4.5 V to 5.5 V		4.0	-	-	4.0	-	4.0	-	ns
t <sub>h</sub>	hold time	D, An to LE; see Figure 9 and Figure 10									
		$V_{CC}$ = 3.0 V to 3.6 V		1.0	-	-	1.0	-	1.0	-	ns
		$V_{CC}$ = 4.5 V to 5.5 V		1.0	-	-	1.0	-	1.0	-	ns
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{\text{CC}}$	<u>[4]</u>	-	13	-	-	-	-	-	pF
74AHCT	-	<sub>C</sub> = 4.5 V to 5.5 V									
t <sub>pd</sub>		D to Qn; see Figure 5	[2]								
	delay	C <sub>L</sub> = 15 pF		-	4.1	7.5	1.0	9.0	1.0	10.0	ns
		C <sub>L</sub> = 50 pF		-	5.4	9.5	1.0	11.0	1.0	12.0	ns
		An to Qn; see Figure 6	[2]								
		C <sub>L</sub> = 15 pF		-	5.5	9.5	1.0	11.5	1.0	12.5	ns
		C <sub>L</sub> = 50 pF		-	6.6	12.0	1.0	14.0	1.0	15.5	ns
		LE to Qn; see Figure 7	[2]								
		C <sub>L</sub> = 15 pF		-	4.3	8.0	1.0	9.5	1.0	10.4	ns
		C <sub>L</sub> = 50 pF		-	5.5	10.0	1.0	12.0	1.0	13.0	ns
		MR to Qn; see Figure 8	<u>[3]</u>								
		C <sub>L</sub> = 15 pF		-	3.9	7.0	1.0	8.5	1.0	9.5	ns
		C <sub>L</sub> = 50 pF		-	5.1	9.0	1.0	10.5	1.0	11.5	ns
t <sub>W</sub>	pulse width	LE HIGH or LOW; see <u>Figure 7</u>		5.0	-	-	5.0	-	5.0	-	ns
		MR LOW; see Figure 8		5.0	-	-	5.0	-	5.0	-	ns
	9_Q100	All information provid									hts res

Table 8.Dynamic characteristics ... continuedVoltages are referenced to GND (around = 0 V); for test circuit, see <a href="#">Figure 11</a>.

**Product data sheet** 

8-bit addressable latch

Voltages	are referenced	d to GND (ground = 0 V); for test ci	rcuit, s	ee <u>Figu</u>	r <u>e 11</u> .					
Symbol	Parameter	Conditions		25 °C		–40 °C to	• +85 °C	–40 °C to	+125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	Min	Max	
t <sub>su</sub>	set-up time	D, An to LE; see <u>Figure 9</u> and <u>Figure 10</u>	4.0	-	-	4.0	-	4.0	-	ns
t <sub>h</sub>	hold time	D, An to LE; see Figure 9 and Figure 10	1.0	-	-	1.0	-	1.0	-	ns
C <sub>PD</sub>	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_1 = \text{GND to } V_{\text{CC}}$ [4]	-	17	-	-	-	-	-	pF

#### Table 8. Dynamic characteristics ... continued

[1] Typical values are measured at nominal supply voltage ( $V_{CC}$  = 3.3 V and  $V_{CC}$  = 5.0 V).

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

#### [3] t<sub>pd</sub> is the same as t<sub>PHL</sub> only.

- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).
  - $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

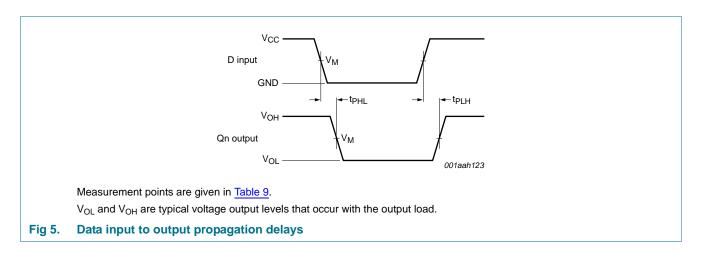
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

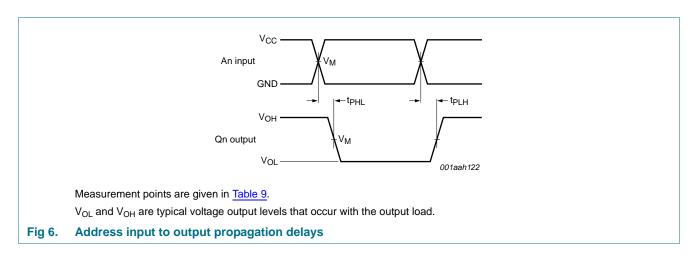
## 11. Waveforms

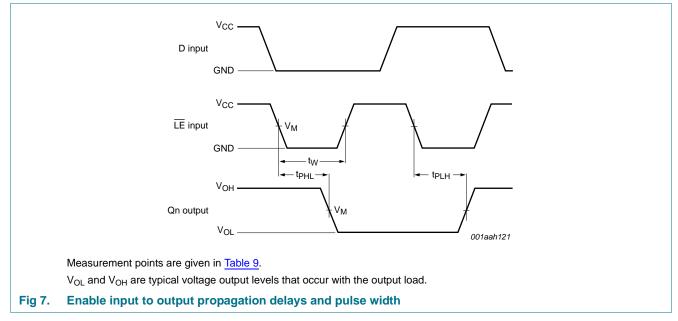


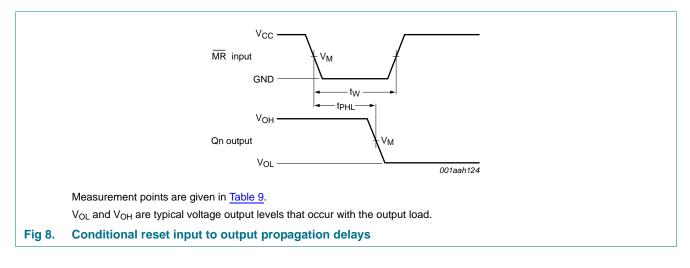
## **NXP Semiconductors**

# 74AHC259-Q100; 74AHCT259-Q100

8-bit addressable latch



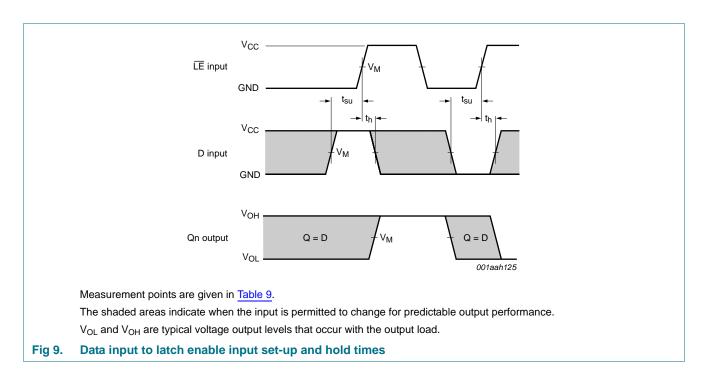


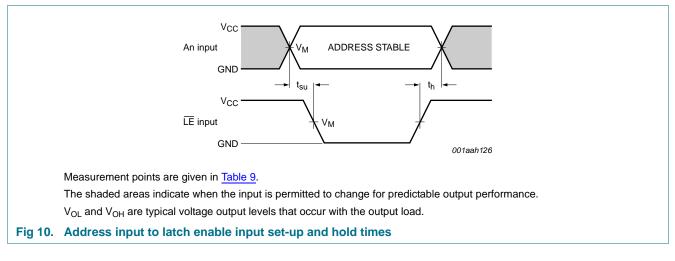


74AHC\_AHCT259\_Q100

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#### 8-bit addressable latch





#### Table 9. Measurement points

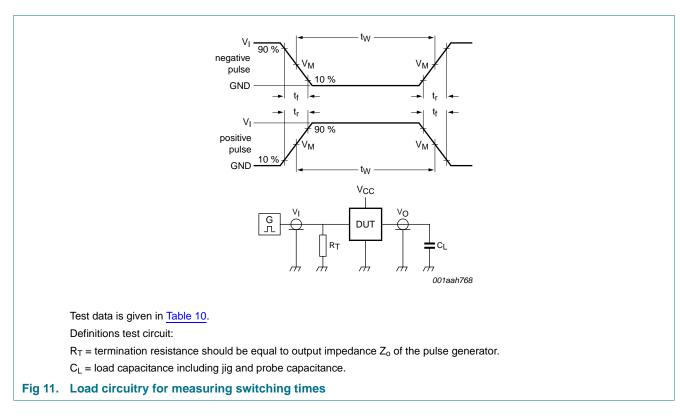
Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74AHC259-Q100	$0.5  imes V_{CC}$	$0.5 \times V_{CC}$
74AHCT259-Q100	1.5 V	$0.5 \times V_{CC}$

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## **NXP Semiconductors**

# 74AHC259-Q100; 74AHCT259-Q100

8-bit addressable latch

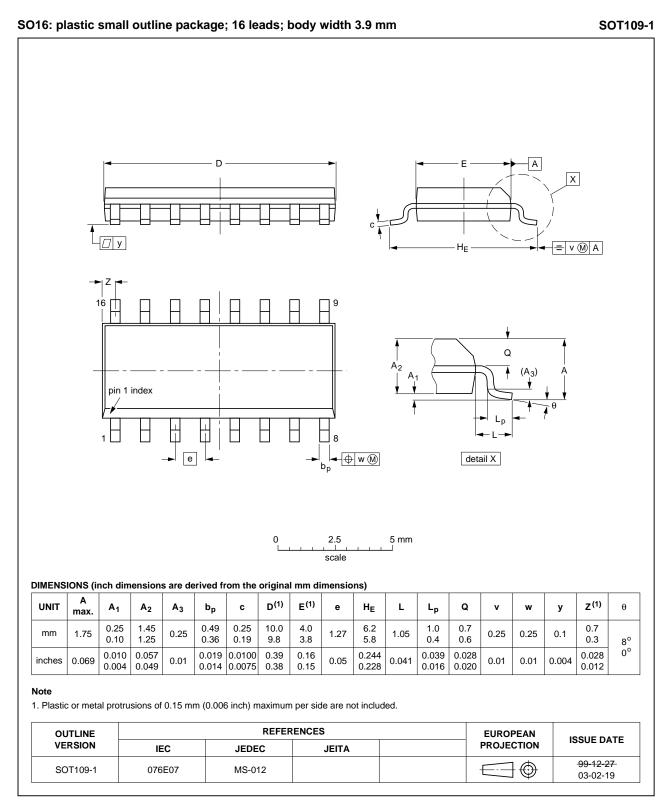


#### Table 10. Test data

Туре	Input		Load	Test
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
74AHC259-Q100	V <sub>CC</sub>	$\leq$ 3.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>
74AHCT259-Q100	3.0 V	$\leq$ 3.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

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## 12. Package outline



#### Fig 12. Package outline SOT109-1 (SO16)

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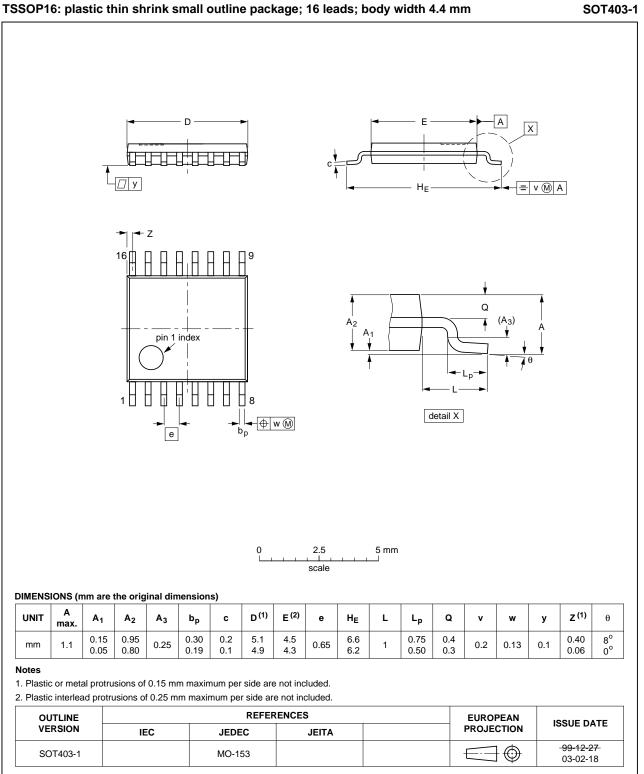


Fig 13. Package outline SOT403-1 (TSSOP16) 74AHC\_AHCT259\_Q100

**Product data sheet** 

## **13. Abbreviations**

Acronym CDM CMOS	Description Charged Device Model Complementary Metal-Oxide Semiconductor
-	
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
MIL	Military
TTL	Transistor-Transistor Logic

## 14. Revision history

Table 12.    Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT259_Q100 v.1	20130722	Product data sheet	-	-

## 15. Legal information

### 15.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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